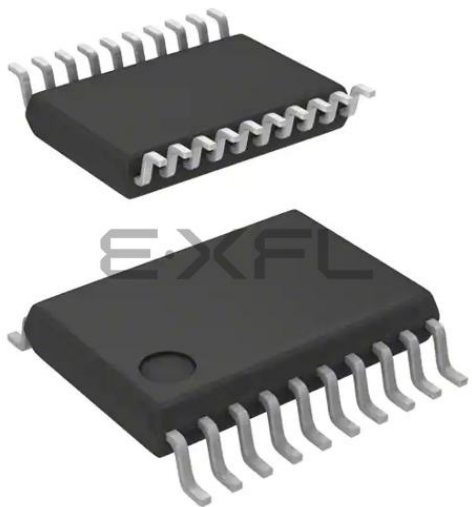




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"[Embedded - Microcontrollers](#)" refer to small, integrated circuits designed to perform specific tasks within larger systems. These microcontrollers are essentially compact computers on a single chip, containing a processor core, memory, and programmable input/output peripherals. They are called "embedded" because they are embedded within electronic devices to control various functions, rather than serving as standalone computers. Microcontrollers are crucial in modern electronics, providing the intelligence and control needed for a wide range of applications.

Applications of "[Embedded - Microcontrollers](#)"

Details

Product Status	Not For New Designs
Core Processor	R8C
Core Size	16-Bit
Speed	20MHz
Connectivity	I ² C, SIO, UART/USART
Peripherals	LED, POR, Voltage Detect, WDT
Number of I/O	13
Program Memory Size	12KB (12K x 8)
Program Memory Type	FLASH
EEPROM Size	-
RAM Size	768 x 8
Voltage - Supply (Vcc/Vdd)	2.7V ~ 5.5V
Data Converters	A/D 4x10b
Oscillator Type	Internal
Operating Temperature	-20°C ~ 85°C (TA)
Mounting Type	Surface Mount
Package / Case	20-LSSOP (0.173", 4.40mm Width)
Supplier Device Package	20-LSSOP
Purchase URL	https://www.e-xfl.com/product-detail/renesas-electronics-america/r5f21163sp-u0

1. Overview

This MCU is built using the high-performance silicon gate CMOS process using the R8C/Tiny Series CPU core and is packaged in a 20-pin plastic molded LSSOP. This MCU operates using sophisticated instructions featuring a high level of instruction efficiency. With 1 Mbyte of address space, it is capable of executing instructions at high speed.

Furthermore, the data flash ROM (1KB × 2blocks) is embedded in the R8C/17 group.

The difference between the R8C/16 and R8C/17 groups is only the existence of the data flash ROM. Their peripheral functions are the same.

1.1 Applications

Electric household appliance, office equipment, housing equipment (sensor, security), general industrial equipment, audio, etc.

1.2 Performance Overview

Table 1.1 lists the Performance Outline of the R8C/16 Group and Table 1.2 lists the Performance Outline of the R8C/17 Group.

Table 1.1 Performance Outline of the R8C/16 Group

Item		Performance
CPU	Number of Basic Instructions	89 instructions
	Minimum Instruction Execution Time	50ns(f(XIN)=20MHz, VCC=3.0 to 5.5V) 100ns(f(XIN)=10MHz, VCC=2.7 to 5.5V)
	Operating Mode	Single-chip
	Address Space	1 Mbyte
	Memory Capacity	See Table 1.3 R8C/16 Group Product Information
Peripheral Function	Port	I/O port : 13 pins (including LED drive port), Input : 2 pins
	LED Drive Port	I/O port: 4 pins
	Timer	Timer X: 8 bits × 1 channel, Timer Z: 8 bits × 1 channel (Each timer equipped with 8-bit prescaler) Timer C: 16 bits × 1 channel (Circuits of input capture and output compare)
	Serial Interface	1 channel Clock synchronous serial I/O, UART
	I ² C bus Interface (IIC) ⁽¹⁾	1 channel
	A/D Converter	10-bit A/D converter: 1 circuit, 4 channels
	Watchdog Timer	15 bits × 1 channel (with prescaler) Reset start selectable, Count source protection mode
	Interrupt	Internal: 9 factors, External: 4 factors, Software: 4 factors Priority level: 7 levels
	Clock Generation Circuit	2 circuits Main clock oscillation circuit (Equipped with a built-in feedback resistor) On-chip oscillator (high speed, low speed) Equipped with frequency adjustment function on high-speed on-chip oscillator
	Oscillation Stop Detection Function	Main clock oscillation stop detection function
	Voltage Detection Circuit	Included
	Power-on Reset Circuit	Included
Electric Characteristics	Supply Voltage	VCC=3.0 to 5.5V (f(XIN)=20MHz) VCC=2.7 to 5.5V (f(XIN)=10MHz)
	Power Consumption	Typ. 9mA (VCC=5.0V, f(XIN)=20MHz) Typ. 5mA (VCC=3.0V, f(XIN)=10MHz) Typ. 35μA (VCC=3.0V, wait mode, peripheral clock off) Typ. 0.7μA (VCC=3.0V, stop mode)
Flash Memory	Program/Erase Supply Voltage	VCC=2.7 to 5.5V
	Program/Erase Endurance	100 times
Operating Ambient Temperature		-20 to 85°C -40 to 85°C (D Version)
Package		20-pin plastic mold LSSOP

NOTES:

1. I²C bus is a trademark of Koninklijke Philips Electronics N. V.

1.4 Product Information

Table 1.3 lists the Product Information of R8C/16 Group and Table 1.4 lists the Product Information of R8C/17 Group.

Table 1.3 Product Information of R8C/16 Group

As of Jan 2006

Type No.	ROM Capacity	RAM Capacity	Package Type	Remarks
R5F21162SP	8 Kbytes	512 bytes	PLSP0020JB-A	Flash Memory Version
R5F21163SP	12 Kbytes	768 bytes	PLSP0020JB-A	
R5F21164SP	16 Kbytes	1 Kbyte	PLSP0020JB-A	
R5F21162DSP	8 Kbytes	512 bytes	PLSP0020JB-A	D Version
R5F21163DSP	12 Kbytes	768 bytes	PLSP0020JB-A	
R5F21164DSP	16 Kbytes	1 Kbyte	PLSP0020JB-A	

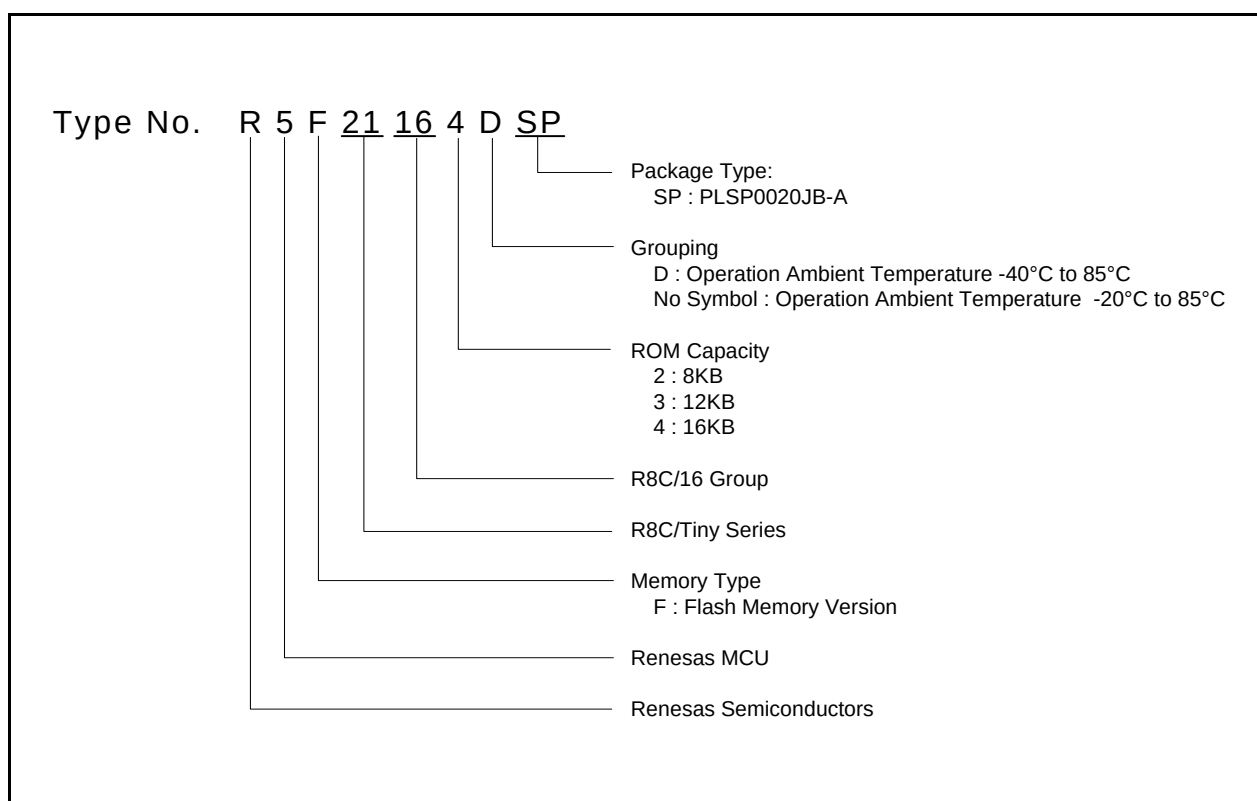


Figure 1.2 Part Number, Memory Size and Package of R8C/16 Group

1.6 Pin Description

Table 1.5 lists the Pin Description and Table 1.6 lists the Pin Name Information by Pin Number.

Table 1.5 Pin Description

Function	Pin Name	I/O Type	Description
Power Supply Input	VCC VSS	I	Apply 2.7V to 5.5V to the VCC pin. Apply 0V to the VSS pin
Analog Power Supply Input	AVCC AVSS	I	Power supply input pins to A/D converter. Connect AVCC to VCC. Apply 0V to AVSS. Connect a capacitor between AVCC and AVSS.
Reset Input	RESET	I	Input "L" on this pin resets the MCU
MODE	MODE	I	Connect this pin to VCC via a resistor
Main Clock Input	XIN	I	These pins are provided for the main clock generation circuit I/O. Connect a ceramic resonator or a crystal oscillator between the XIN and XOUT pins. To use an externally derived clock, input it to the XIN pin and leave the XOUT pin open.
Main Clock Output	XOUT	O	
INT Interrupt	INT0, INT1, INT3	I	INT interrupt input pins
Key Input Interrupt	KI0 to KI3	I	Key input interrupt input pins
Timer X	CNTR0	I/O	Timer X I/O pin
	CNTR0	O	Timer X output pin
Timer Z	TZOUT	O	Timer Z output pin
Timer C	TCIN	I	Timer C input pin
	CMP0_0 to CMP0_2, CMP1_0 to CMP1_2	O	Timer C output pins
Serial Interface	CLK0	I/O	Transfer clock I/O pin
	RXD0	I	Serial data input pin
	TXD0	O	Serial data output pin
I ² C bus Interface (IIC)	SCL	I/O	Clock I/O pin
	SDA	I/O	Data I/O pin
Reference Voltage Input	VREF	I	Reference voltage input pin to A/D converter Connect VREF to VCC
A/D Converter	AN8 to AN11	I	Analog input pins to A/D converter
I/O Port	P1_0 to P1_7, P3_3 to P3_5, P3_7, P4_5	I/O	These are CMOS I/O ports. Each port contains an I/O select direction register, allowing each pin in that port to be directed for input or output individually. Any port set to input can select whether to use a pull-up resistor or not by program. P1_0 to P1_3 also function as LED drive ports.
Input Port	P4_6, P4_7	I	Port for input-only

I: Input O: Output I/O: Input and output

2.8.7 Interrupt Enable Flag (I)

The I flag enables a maskable interrupt.

An interrupt is disabled when the I flag is set to "0", and are enabled when the I flag is set to "1". The I flag is set to "0" when an interrupt request is acknowledged.

2.8.8 Stack Pointer Select Flag (U)

ISP is selected when the U flag is set to "0", USP is selected when the U flag is set to "1".

The U flag is set to "0" when a hardware interrupt request is acknowledged or the INT instruction of software interrupt numbers 0 to 31 is executed.

2.8.9 Processor Interrupt Priority Level (IPL)

IPL, 3 bits wide, assigns processor interrupt priority levels from level 0 to level 7.

If a requested interrupt has greater priority than IPL, the interrupt is enabled.

2.8.10 Reserved Bit

When write to this bit, set to "0". When read, its content is indeterminate.

3. Memory

3.1 R8C/16 Group

Figure 3.1 is a Memory Map of the R8C/16 group. The R8C/16 group provides 1-Mbyte address space from addresses 00000h to FFFFFh.

The internal ROM is allocated lower addresses beginning with address 0C000h. For example, a 16-Kbyte internal ROM is allocated addresses 0C000h to 0FFFFh.

The fixed interrupt vector table is allocated addresses 0FFDCh to 0FFFFh. They store the starting address of each interrupt routine.

The internal RAM is allocated higher addresses beginning with address 00400h. For example, a 1-Kbyte internal RAM is allocated addresses 00400h to 007FFh. The internal RAM is used not only for storing data but for calling subroutines and stacks when interrupt request is acknowledged.

Special function registers (SFR) are allocated addresses 00000h to 002FFh. The peripheral function control registers are allocated them. All addresses, which have nothing allocated within the SFR, are reserved area and cannot be accessed by users.

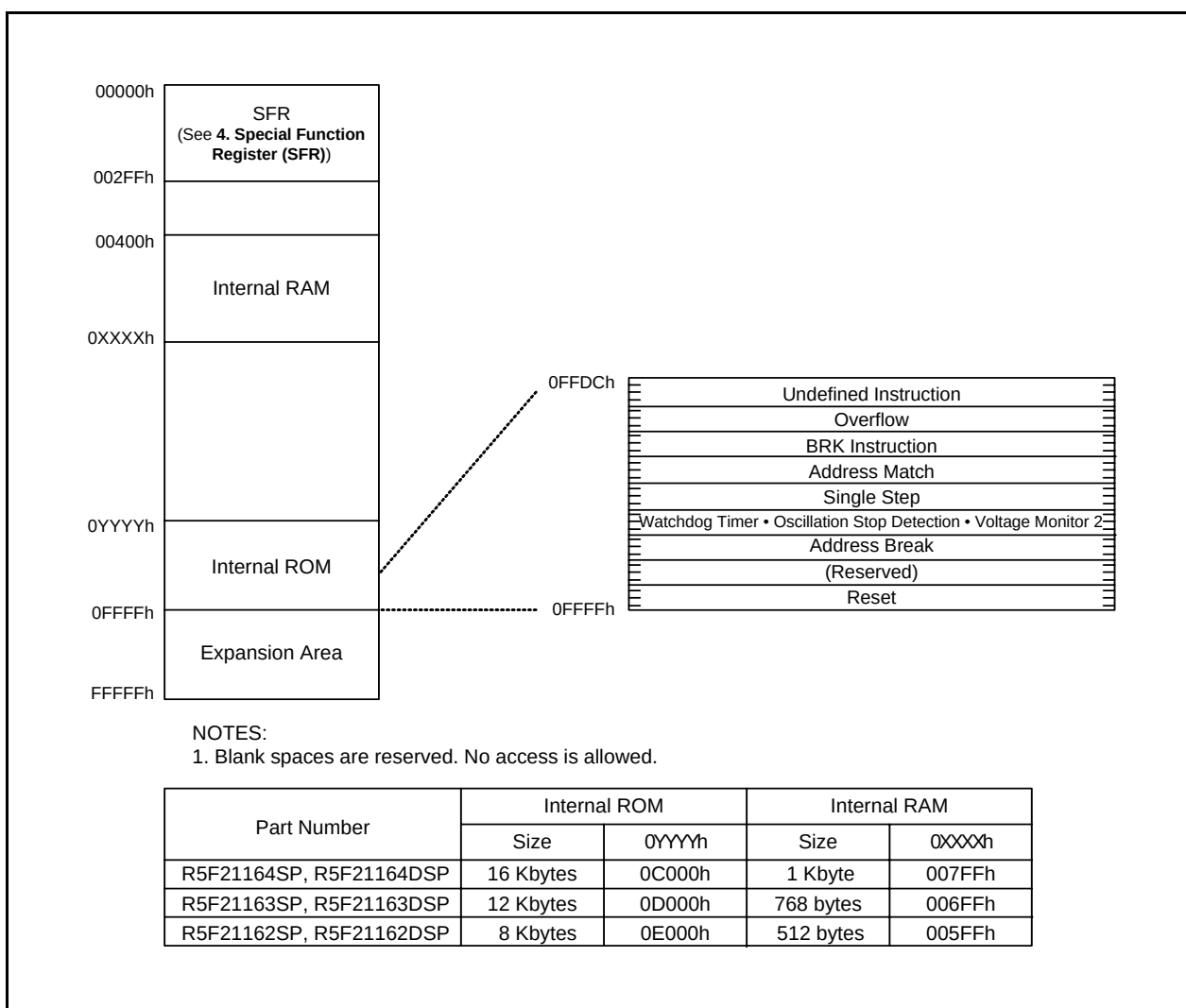


Figure 3.1 Memory Map of R8C/16 Group

4. Special Function Register (SFR)

SFR (Special Function Register) is the control register of peripheral functions. Tables 4.1 to 4.4 list the SFR information.

Table 4.1 SFR Information(1)(1)

Address	Register	Symbol	After Reset
0000h			
0001h			
0002h			
0003h			
0004h	Processor Mode Register 0	PM0	00h
0005h	Processor Mode Register 1	PM1	00h
0006h	System Clock Control Register 0	CM0	01101000b
0007h	System Clock Control Register 1	CM1	00100000b
0008h			
0009h	Address Match Interrupt Enable Register	AIER	00h
000Ah	Protect Register	PRCR	00h
000Bh			
000Ch	Oscillation Stop Detection register	OSD	00000100b
000Dh	Watchdog Timer Reset Register	WDTR	XXh
000Eh	Watchdog Timer Start Register	WDTS	XXh
000Fh	Watchdog Timer Control Register	WDC	00011111b
0010h	Address Match Interrupt Register 0	RMAD0	00h
0011h			00h
0012h			X0h
0013h			
0014h	Address Match Interrupt Register 1	RMAD1	00h
0015h			00h
0016h			X0h
0017h			
0018h			
0019h			
001Ah			
001Bh			
001Ch	Count Source Protection Mode Register	CSPR	00h
001Dh			
001Eh	INT0 Input Filter Select Register	INT0F	00h
001Fh			
0020h	High-Speed On-Chip Oscillator Control Register 0	HRA0	00h
0021h	High-Speed On-Chip Oscillator Control Register 1	HRA1	When shipping
0022h	High-Speed On-Chip Oscillator Control Register 2	HRA2	00h
0023h			
0024h			
0025h			
0026h			
0027h			
0028h			
0029h			
002Ah			
002Bh			
002Ch			
002Dh			
002Eh			
002Fh			
0030h			
0031h	Voltage Detection Register 1 ⁽²⁾	VCA1	00001000b
0032h	Voltage Detection Register 2 ⁽²⁾	VCA2	00h ⁽³⁾ 01000000b ⁽⁴⁾
0033h			
0034h			
0035h			
0036h	Voltage Monitor 1 Circuit Control Register ⁽²⁾	VW1C	0000X000b ⁽³⁾ 0100X001b ⁽⁴⁾
0037h	Voltage Monitor 2 Circuit Control Register ⁽⁵⁾	VW2C	00h
0038h			
0039h			
003Ah			
003Bh			
003Ch			
003Dh			
003Eh			
003Fh			

X: Undefined

NOTES:

- Blank spaces are reserved. No access is allowed.
- Software reset, the watchdog timer reset or the voltage monitor 2 reset does not affect this register.
- Owing to Hardware reset.
- Owing to Power-on reset or the voltage monitor 1 reset.
- Software reset, the watchdog timer reset or the voltage monitor 2 reset does not affect the b2 and b3.

Table 4.2 SFR Information(2)(1)

Address	Register	Symbol	After reset
0040h			
0041h			
0042h			
0043h			
0044h			
0045h			
0046h			
0047h			
0048h			
0049h			
004Ah			
004Bh			
004Ch			
004Dh	Key Input Interrupt Control Register	KUPIC	XXXXX000b
004Eh	A/D Conversion Interrupt Control Register	ADIC	XXXXX000b
004Fh	IIC Interrupt Control Register	IIC2AIC	XXXXX000b
0050h	Compare 1 Interrupt Control Register	CMP1IC	XXXXX000b
0051h	UART0 Transmit Interrupt Control Register	S0TIC	XXXXX000b
0052h	UART0 Receive Interrupt Control Register	S0RIC	XXXXX000b
0053h			
0054h			
0055h			
0056h	Timer X Interrupt Control Register	TXIC	XXXXX000b
0057h			
0058h	Timer Z Interrupt Control Register	TZIC	XXXXX000b
0059h	INT1 Interrupt Control Register	INT1IC	XXXXX000b
005Ah	INT3 Interrupt Control Register	INT3IC	XXXXX000b
005Bh	Timer C Interrupt Control Register	TCIC	XXXXX000b
005Ch	Compare 0 Interrupt Control Register	CMP0IC	XXXXX000b
005Dh	INT0 Interrupt Control Register	INT0IC	XX00X000b
005Eh			
005Fh			
0060h			
0061h			
0062h			
0063h			
0064h			
0065h			
0066h			
0067h			
0068h			
0069h			
006Ah			
006Bh			
006Ch			
006Dh			
006Eh			
006Fh			
0070h			
0071h			
0072h			
0073h			
0074h			
0075h			
0076h			
0077h			
0078h			
0079h			
007Ah			
007Bh			
007Ch			
007Dh			
007Eh			
007Fh			

X: Undefined

NOTES:

- Blank spaces are reserved. No access is allowed.

5. Electrical Characteristics

Table 5.1 Absolute Maximum Ratings

Symbol	Parameter	Condition	Rated value	Unit
V _{CC}	Supply Voltage	V _{CC} = AV _{CC}	-0.3 to 6.5	V
AV _{CC}	Analog Supply Voltage	V _{CC} = AV _{CC}	-0.3 to 6.5	V
V _I	Input Voltage		-0.3 to V _{CC} +0.3	V
V _O	Output Voltage		-0.3 to V _{CC} +0.3	V
P _d	Power Dissipation	T _{opr} = 25°C	300	mW
T _{opr}	Operating Ambient Temperature		-20 to 85 / -40 to 85 (D version)	°C
T _{stg}	Storage Temperature		-65 to 150	°C

Table 5.2 Recommended Operating Conditions

Symbol	Parameter		Conditions	Standard			Unit
				Min.	Typ.	Max.	
V _{CC}	Supply Voltage			2.7	–	5.5	V
AV _{CC}	Analog Supply Voltage			–	V _{CC} (3)	–	V
V _{SS}	Supply Voltage			–	0	–	V
AV _{SS}	Analog Supply Voltage			–	0	–	V
V _{IH}	Input “H” Voltage			0.8V _{CC}	–	V _{CC}	V
V _{IL}	Input “L” Voltage			0	–	0.2V _{CC}	V
I _{OH} (sum)	Peak Sum Output “H” Current	Sum of All Pins I _{OH} (peak)		–	–	-60	mA
I _{OH} (peak)	Peak Output “H” Current			–	–	-10	mA
I _{OH} (avg)	Average Output “H” Current			–	–	-5	mA
I _{OL} (sum)	Peak Sum Output “L” Currents	Sum of All Pins I _{OL} (peak)		–	–	60	mA
I _{OL} (peak)	Peak Output “L” Currents	Except P1_0 to P1_3		–	–	10	mA
		P1_0 to P1_3	Drive Capacity HIGH	–	–	30	mA
			Drive Capacity LOW	–	–	10	mA
I _{OL} (avg)	Average Output “L” Current	Except P1_0 to P1_3		–	–	5	mA
		P1_0 to P1_3	Drive Capacity HIGH	–	–	15	mA
			Drive Capacity LOW	–	–	5	mA
f _(XIN)	Main Clock Input Oscillation Frequency		3.0V ≤ V _{CC} ≤ 5.5V	0	–	20	MHz
			2.7V ≤ V _{CC} < 3.0V	0	–	10	MHz

NOTES:

1. V_{CC} = AV_{CC} = 2.7 to 5.5V at T_{opr} = -20 to 85 °C / -40 to 85 °C, unless otherwise specified.
2. The typical values when average output current is 100ms.
3. Hold V_{CC} = AV_{CC}.

Table 5.3 A/D Converter Characteristics

Symbol	Parameter		Conditions	Standard			Unit
				Min.	Typ.	Max.	
—	Resolution		$V_{ref} = V_{CC}$	—	—	10	Bits
—	Absolute Accuracy	10-Bit Mode	$\phi_{AD} = 10\text{MHz}$, $V_{ref} = V_{CC} = 5.0\text{V}$	—	—	± 3	LSB
		8-Bit Mode	$\phi_{AD} = 10\text{MHz}$, $V_{ref} = V_{CC} = 5.0\text{V}$	—	—	± 2	LSB
		10-Bit Mode	$\phi_{AD} = 10\text{MHz}$, $V_{ref} = V_{CC} = 3.3\text{V}^{(3)}$	—	—	± 5	LSB
		8-Bit Mode	$\phi_{AD} = 10\text{MHz}$, $V_{ref} = V_{CC} = 3.3\text{V}^{(3)}$	—	—	± 2	LSB
R_{ladder}	Resistor Ladder		$V_{ref} = V_{CC}$	10	—	40	$k\Omega$
t_{conv}	Conversion Time	10-Bit Mode	$\phi_{AD} = 10\text{MHz}$, $V_{ref} = V_{CC} = 5.0\text{V}$	3.3	—	—	μs
		8-Bit Mode	$\phi_{AD} = 10\text{MHz}$, $V_{ref} = V_{CC} = 5.0\text{V}$	2.8	—	—	μs
V_{ref}	Reference voltage			—	$V_{CC}^{(4)}$	—	V
V_{IA}	Analog Input Voltage			0	—	V_{ref}	V
—	A/D Operating Clock Frequency ⁽²⁾	Without Sample & Hold		0.25	—	10	MHz
		With Sample & Hold		1	—	10	MHz

NOTES:

1. $V_{CC} = AV_{CC} = 2.7$ to 5.5V at $T_{opr} = -20$ to $85\text{ }^{\circ}\text{C}$ / -40 to $85\text{ }^{\circ}\text{C}$, unless otherwise specified.
2. If f_1 exceeds 10MHz , divide the f_1 and hold A/D operating clock frequency (ϕ_{AD}) 10MHz or below.
3. If the AV_{CC} is less than 4.2V , divide the f_1 and hold A/D operating clock frequency (ϕ_{AD}) $f_1/2$ or below.
4. Hold $V_{CC} = V_{ref}$

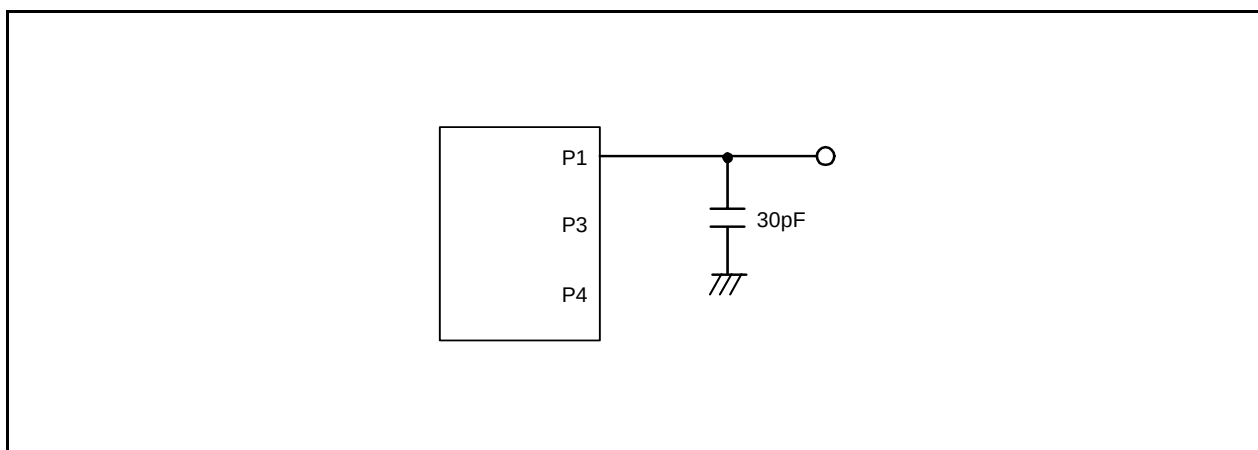
**Figure 5.1 Port P1, P3 and P4 Measurement Circuit**

Table 5.8 Reset Circuit Electrical Characteristics (When Using Voltage Monitor 1 Reset)

Symbol	Parameter	Condition	Standard			Unit
			Min.	Typ.	Max.	
V _{por2}	Power-On Reset Valid Voltage	-20°C ≤ Topr < 85°C	—	—	V _{det1}	V
t _w (V _{por2} -V _{det1})	Supply Voltage Rising Time When Power-On Reset is Deasserted ⁽¹⁾	-20°C ≤ Topr < 85°C, t _w (por2) ≥ 0s ⁽³⁾	—	—	100	ms

NOTES:

1. This condition is not applicable when using with V_{cc} ≥ 1.0V.
2. When turning power on after the time to hold the external power below effective voltage (V_{por1}) exceeds 10s, refer to **Table 5.9 Reset Circuit Electrical Characteristics (When Not Using Voltage Monitor 1 Reset)**.
3. t_w(por2) is time to hold the external power below effective voltage (V_{por2}).

Table 5.9 Reset Circuit Electrical Characteristics (When Not Using Voltage Monitor 1 Reset)

Symbol	Parameter	Condition	Standard			Unit
			Min.	Typ.	Max.	
V _{por1}	Power-On Reset Valid Voltage	-20°C ≤ Topr < 85°C	—	—	0.1	V
t _w (V _{por1} -V _{det1})	Supply Voltage Rising Time When Power-On Reset is Deasserted	0°C ≤ Topr ≤ 85°C, t _w (por1) ≥ 10s ⁽²⁾	—	—	100	ms
t _w (V _{por1} -V _{det1})	Supply Voltage Rising Time When Power-On Reset is Deasserted	-20°C ≤ Topr < 0°C, t _w (por1) ≥ 30s ⁽²⁾	—	—	100	ms
t _w (V _{por1} -V _{det1})	Supply Voltage Rising Time When Power-On Reset is Deasserted	-20°C ≤ Topr < 0°C, t _w (por1) ≥ 10s ⁽²⁾	—	—	1	ms
t _w (V _{por1} -V _{det1})	Supply Voltage Rising Time When Power-On Reset is Deasserted	0°C ≤ Topr ≤ 85°C, t _w (por1) ≥ 1s ⁽²⁾	—	—	0.5	ms

NOTES:

1. When not using the voltage monitor 1 reset, use with V_{cc} ≥ 2.7V.
2. t_w(por1) is time to hold the external power below effective voltage (V_{por1}).

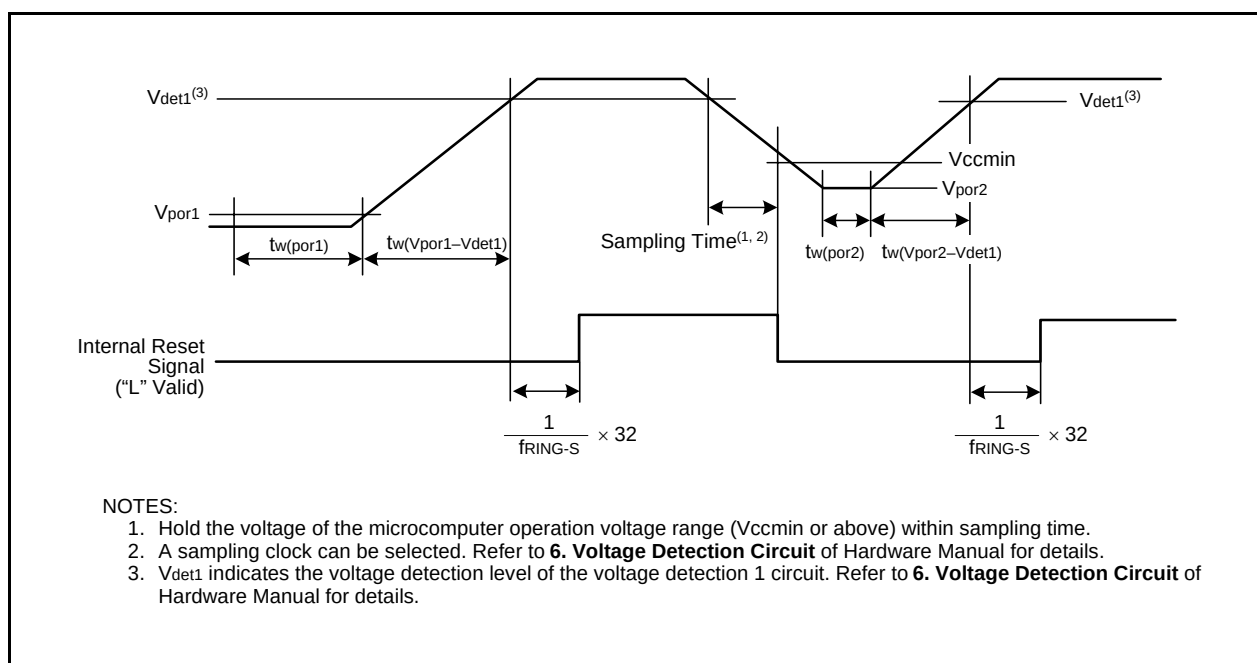
**Figure 5.3 Reset Circuit Electrical Characteristics**

Table 5.10 High-speed On-Chip Oscillator Circuit Electrical Characteristics

Symbol	Parameter	Condition	Standard			Unit
			Min.	Typ.	Max.	
—	High-Speed On-Chip Oscillator Frequency When the Reset is Deasserted	$V_{CC} = 5.0V$, $T_{opr} = 25\text{ }^{\circ}\text{C}$	—	8	—	MHz
—	High-Speed On-Chip Oscillator Frequency Temperature • Supply Voltage Dependence	0 to +60 $^{\circ}\text{C}$ / 5 V $\pm$ 5 % ⁽²⁾	7.44	—	8.56	MHz
		–20 to +85 $^{\circ}\text{C}$ / 2.7 to 5.5 V ⁽²⁾	7.04	—	8.96	MHz
		–40 to +85 $^{\circ}\text{C}$ / 2.7 to 5.5 V ⁽²⁾	6.80	—	9.20	MHz

NOTES:

1. The measurement condition is $V_{CC} = AV_{CC} = 5.0V$ and $T_{opr} = 25\text{ }^{\circ}\text{C}$.
2. The standard value shows when the HRA1 register is assumed as the value in shipping and the HRA2 register value is set to 00h.

Table 5.11 Power Supply Circuit Timing Characteristics

Symbol	Parameter	Condition	Standard			Unit
			Min.	Typ.	Max.	
$t_{d(P-R)}$	Time for Internal Power Supply Stabilization during Power-On ⁽²⁾		1	—	2000	μs
$t_{d(R-S)}$	STOP Exit Time ⁽³⁾		—	—	150	μs

NOTES:

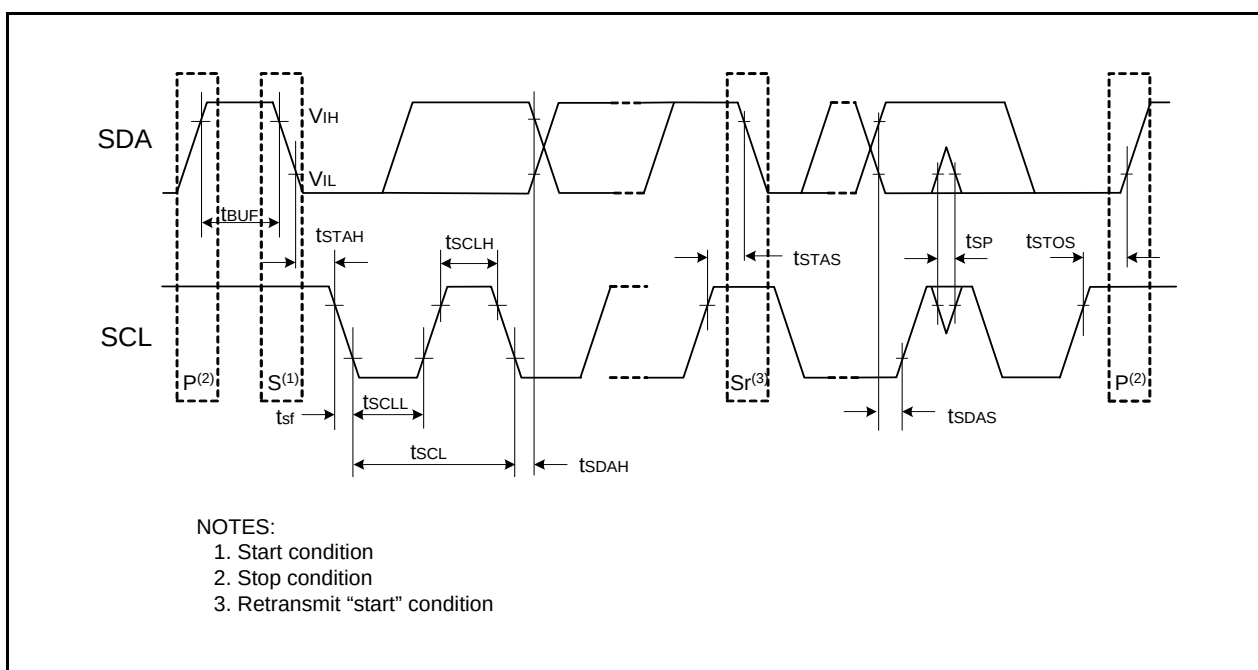
1. The measurement condition is $V_{CC} = AV_{CC} = 2.7$ to $5.5V$ and $T_{opr} = 25\text{ }^{\circ}\text{C}$.
2. Waiting time until the internal power supply generation circuit stabilizes during power-on.
3. Time until CPU clock supply starts since the interrupt is acknowledged to exit stop mode.

Table 5.12 Timing Requirements of I²C bus Interface (IIC) ⁽¹⁾

Symbol	Parameter	Condition	Standard			Unit
			Min.	Typ.	Max.	
t _{SCL}	SCL Input Cycle Time		12t _{CYC} +600 ⁽²⁾	—	—	ns
t _{SCLH}	SCL Input "H" Width		3t _{CYC} +300 ⁽²⁾	—	—	ns
t _{SCLL}	SCL Input "L" Width		5t _{CYC} +300 ⁽²⁾	—	—	ns
t _{sf}	SCL, SDA Input Fall Time		—	—	300	ns
t _{SP}	SCL, SDA Input Spike Pulse Rejection Time		—	—	1t _{CYC} ⁽²⁾	ns
t _{BUF}	SDA Input Bus-Free Time		5t _{CYC} ⁽²⁾	—	—	ns
t _{STAH}	Start Condition Input Hold Time		3t _{CYC} ⁽²⁾	—	—	ns
t _{STAS}	Retransmit Start Condition Input SetUp Time		3t _{CYC} ⁽²⁾	—	—	ns
t _{STOS}	Stop Condition Input SetUp Time		3t _{CYC} ⁽²⁾	—	—	ns
t _{SDAS}	Data Input SetUp Time		1t _{CYC} +20 ⁽²⁾	—	—	ns
t _{SDAH}	Data Input Hold Time		0	—	—	ns

NOTES:

1. V_{CC} = AV_{CC} = 2.7 to 5.5V, V_{SS} = 0V and Topr = -20 to 85 °C / -40 to 85 °C, unless otherwise specified.
2. 1t_{CYC}=1/f₁(s)

**Figure 5.4** I/O Timing of I²C bus Interface (IIC)

Timing Requirements (Unless otherwise specified: V_{CC} = 5V, V_{SS} = 0V at Topr = 25 °C) [V_{CC} = 5V]**Table 5.15 XIN Input**

Symbol	Parameter	Standard		Unit
		Min.	Max.	
t _c (XIN)	XIN Input Cycle Time	50	–	ns
t _{WH} (XIN)	XIN Input "H" Width	25	–	ns
t _{WL} (XIN)	XIN Input "L" Width	25	–	ns

Table 5.16 CNTR0 Input, CNTR1 Input, $\overline{\text{INT1}}$ Input

Symbol	Parameter	Standard		Unit
		Min.	Max.	
t _c (CNTR0)	CNTR0 Input Cycle Time	100	–	ns
t _{WH} (CNTR0)	CNTR0 Input "H" Width	40	–	ns
t _{WL} (CNTR0)	CNTR0 input "L" Width	40	–	ns

Table 5.17 TCIN Input, $\overline{\text{INT3}}$ Input

Symbol	Parameter	Standard		Unit
		Min.	Max.	
t _c (TCIN)	TCIN Input Cycle Time	400 ⁽¹⁾	–	ns
t _{WH} (TCIN)	TCIN Input "H" Width	200 ⁽²⁾	–	ns
t _{WL} (TCIN)	TCIN input "L" Width	200 ⁽²⁾	–	ns

NOTES:

1. When using Timer C input capture mode, adjust the cycle time (1/ Timer C count source frequency x 3) or above.
2. When using Timer C input capture mode, adjust the width (1/ Timer C count source frequency x 1.5) or above.

Table 5.18 Serial Interface

Symbol	Parameter	Standard		Unit
		Min.	Max.	
t _c (CK)	CLKi Input Cycle Time	200	–	ns
t _w (CKH)	CLKi Input "H" Width	100	–	ns
t _w (CKL)	CLKi Input "L" Width	100	–	ns
t _d (C-Q)	TXDi Output Delay Time	–	50	ns
t _h (C-Q)	TXDi Hold Time	0	–	ns
t _{su} (D-C)	RXDi Input Setup Time	50	–	ns
t _h (C-D)	RCDi Input Hold Time	90	–	ns

Table 5.19 External Interrupt $\overline{\text{INT0}}$ Input

Symbol	Parameter	Standard		Unit
		Min.	Max.	
t _w (INH)	$\overline{\text{INT0}}$ Input "H" Width	250 ⁽¹⁾	–	ns
t _w (INL)	$\overline{\text{INT0}}$ Input "L" Width	250 ⁽²⁾	–	ns

NOTES:

1. When selecting the digital filter by the $\overline{\text{INT0}}$ input filter select bit, use the $\overline{\text{INT0}}$ input HIGH width to the greater value, either (1/ digital filter clock frequency x 3) or the minimum value of standard.
2. When selecting the digital filter by the $\overline{\text{INT0}}$ input filter select bit, use the $\overline{\text{INT0}}$ input LOW width to the greater value, either (1/ digital filter clock frequency x 3) or the minimum value of standard.

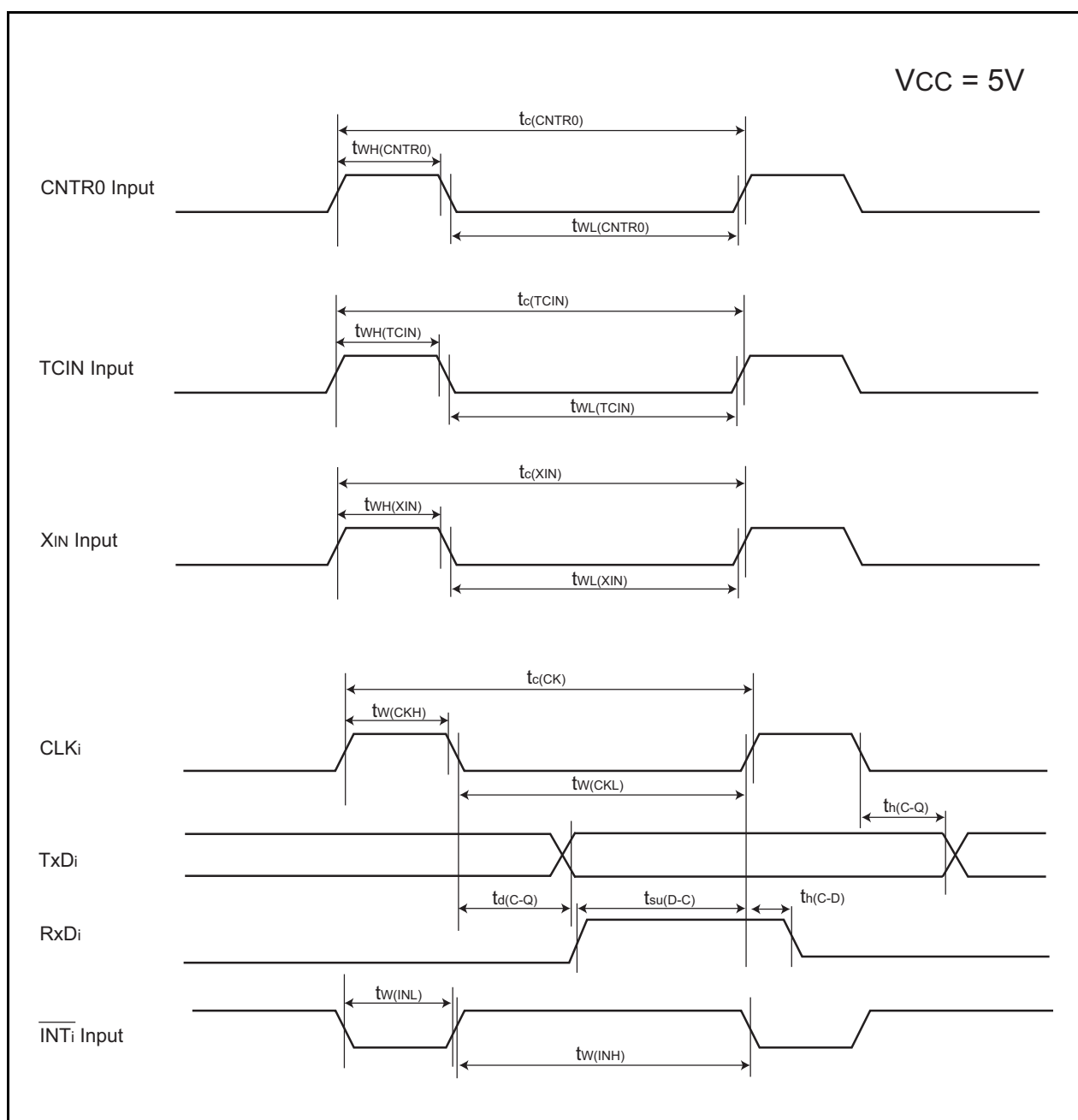


Figure 5.5 Timing Diagram When $V_{CC} = 5V$

Table 5.20 Electrical Characteristics (3) [Vcc = 3V]

Symbol	Parameter		Condition		Standard			Unit
					Min.	Typ.	Max.	
VOH	Output "H" Voltage	Except XOUT	IOH = -1mA		Vcc - 0.5	-	Vcc	V
		XOUT	Drive capacity HIGH	IOH = -0.1mA	Vcc - 0.5	-	Vcc	V
			Drive capacity LOW	IOH = -50μA	Vcc - 0.5	-	Vcc	V
VOL	Output "L" Voltage	Except P1_0 to P1_3, XOUT	IOL = 1mA		-	-	0.5	V
		P1_0 to P1_3	Drive capacity HIGH	IOL = 2mA	-	-	0.5	V
			Drive capacity LOW	IOL = 1mA	-	-	0.5	V
		XOUT	Drive capacity HIGH	IOL = 0.1mA	-	-	0.5	V
			Drive capacity LOW	IOL = 50μA	-	-	0.5	V
VT+-VT-	Hysteresis	INT0, INT1, INT3, KI0, KI1, KI2, KI3, CNTR0, CNTR1, TCIN, RXD0			0.2	-	0.8	V
		RESET			0.2	-	1.8	V
IiH	Input "H" Current		VI = 3V		-	-	4.0	μA
IiL	Input "L" Current		VI = 0V		-	-	-4.0	μA
RPULLUP	Pull-Up Resistance		VI = 0V		66	160	500	kΩ
RfXIN	Feedback Resistance	XIN			-	3.0	-	MΩ
fRING-S	Low-Speed On-Chip Oscillator Frequency				40	125	250	kHz
VRAM	RAM Hold Voltage		During stop mode		2.0	-	-	V

NOTES:

- Vcc = AVcc = 2.7 to 3.3V at Topr = -20 to 85 °C / -40 to 85 °C, f(XIN)=10MHz, unless otherwise specified.

Timing requirements (Unless otherwise specified: $V_{CC} = 3V$, $V_{SS} = 0V$ at $T_{opr} = 25\text{ }^{\circ}C$) [$V_{CC} = 3V$]**Table 5.22 XIN Input**

Symbol	Parameter	Standard		Unit
		Min.	Max.	
$t_{c(XIN)}$	XIN Input Cycle Time	100	–	ns
$t_{WH(XIN)}$	XIN Input "H" Width	40	–	ns
$t_{WL(XIN)}$	XIN Input "L" Width	40	–	ns

Table 5.23 CNTR0 Input, CNTR1 Input, $\overline{INT1}$ Input

Symbol	Parameter	Standard		Unit
		Min.	Max.	
$t_{c(CNTR0)}$	CNTR0 Input Cycle Time	300	–	ns
$t_{WH(CNTR0)}$	CNTR0 Input "H" Width	120	–	ns
$t_{WL(CNTR0)}$	CNTR0 Input "L" Width	120	–	ns

Table 5.24 TCIN Input, $\overline{INT3}$ Input

Symbol	Parameter	Standard		Unit
		Min.	Max.	
$t_{c(TCIN)}$	TCIN Input Cycle Time	1,200 ⁽¹⁾	–	ns
$t_{WH(TCIN)}$	TCIN Input "H" Width	600 ⁽²⁾	–	ns
$t_{WL(TCIN)}$	TCIN Input "L" Width	600 ⁽²⁾	–	ns

NOTES:

1. When using the Timer C input capture mode, adjust the cycle time (1/ Timer C count source frequency x 3) or above.
2. When using the Timer C input capture mode, adjust the width (1/ Timer C count source frequency x 1.5) or above.

Table 5.25 Serial Interface

Symbol	Parameter	Standard		Unit
		Min.	Max.	
$t_{c(CLKi)}$	CLKi Input Cycle Time	300	–	ns
$t_{w(CLKH)}$	CLKi Input "H" Width	150	–	ns
$t_{w(CLKL)}$	CLKi Input "L" Width	150	–	ns
$t_{d(C-Q)}$	TXDi Output Delay Time	–	80	ns
$t_{h(C-Q)}$	TXDi Hold Time	0	–	ns
$t_{su(D-C)}$	RXDi Input Setup Time	70	–	ns
$t_{h(C-D)}$	RCDi Input Hold Time	90	–	ns

Table 5.26 External Interrupt $\overline{INT0}$ Input

Symbol	Parameter	Standard		Unit
		Min.	Max.	
$t_{w(INH)}$	$\overline{INT0}$ Input "H" Width	380 ⁽¹⁾	–	ns
$t_{w(INL)}$	$\overline{INT0}$ Input "L" Width	380 ⁽²⁾	–	ns

NOTES:

1. When selecting the digital filter by the $\overline{INT0}$ input filter select bit, use the $\overline{INT0}$ input HIGH width to the greater value, either (1/ digital filter clock frequency x 3) or the minimum value of standard.
2. When selecting the digital filter by the $\overline{INT0}$ input filter select bit, use the $\overline{INT0}$ input LOW width to the greater value, either (1/ digital filter clock frequency x 3) or the minimum value of standard.

REVISION HISTORY	R8C/16 Group, R8C/17 Group Datasheet
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Rev.	Date	Description	
		Page	Summary
0.10	Sep 06, 2004	–	First Edition issued
1.00	Feb 25, 2005	2-3 5 6 7-8 16 18 21 22 24 25 26 27 28 29, 33 31 32 35	Tables 1.1 and 1.2 revised Table 1.3 and figure 1.2 revised Table 1.4 and figure 1.3 revised Figures 1.4 and 1.5 revised Table 4.1 revised: - 000Fh: 000XXXXXb → 00011111b - 0036h: 00001000b → 0000X000b and 01001001b → 0100X001b Tabel 4.3 revised: - 009Ch: FFh → 00h; NOTES2 added - 009Dh: FFh → 00h Table 5.3 revised Tables 5.4 and 5.5 revised Tables 5.8 and 5.9 revised Table 5.11 revised Table 5.12 and figure 5.4 added Table 5.13 revised Table 5.14 revised Table 5.16 and 5.23 revised: Table title “INT2” → “INT1” Table 5.20 revised; NOTE revised Table 5.21 revised Package Dimensions revised
1.10	May 26, 2005	5, 6 16 22 26 27 31	Tables 1.3 and 1.4 revised Table 4.1 revised: - 0009h: XXXXXX00b → 00h - 000Ah: 00XXX000b → 00h - 001Eh: XXXXX000b → 00h Table 5.5 revised; NOTE revised Fig 5.4 revised Table 5.13 revised Table 5.20 revised
2.00	Jan 30, 2006	1 2 3 4 5, 6	1. Overview; “20-pin plastic molded LSSOP or SDIP” → “20-pin plastic molded LSSOP” revised Table 1.1 Performance Outline of the R8C/16 Group; Package: “20-pin plastic molded SDIP” deleted Table 1.2 Performance Outline of the R8C/17 Group; Package: “20-pin plastic molded SDIP” deleted, Flash Memory: (Data area) → (Data flash) (Program area) → (Program ROM) revised Figure 1.1 Block Diagram; “Peripheral Function” added, “System Clock Generation” → “System Clock Generator” revised Table 1.3 Product Information of R8C/16 Group, Table 1.4 Product Information of R8C/17 Group; revised. Figure 1.2 Part Number, Memory Size and Package of R8C/16 Group, Figure 1.3 Part Number, Memory Size and Package of R8C/17 Group; Package type: “DD : PRDP0020BA-A” deleted

REVISION HISTORY

R8C/16 Group, R8C/17 Group Datasheet

Rev.	Date	Description	
		Page	Summary
2.00	Jan 30, 2006	8	Figure 1.5 PRDP0020BA-A Package Pin Assignment (top view) deleted Table 1.5 Pin Description; Timer C: "CMP0_0 to CMP0_3, CMP1_0 to CMP1_3" → "CMP0_0 to CMP0_2, CMP1_0 to CMP1_2" revised
		10	Figure 2.1 CPU Register; "Reserved Area" → "Reserved Bit" revised
		12	2.8.10 Reserved Area; "Reserved Area" → "Reserved Bit" revised
		13	Figure 3.1 Memory Map of R8C/16 Group revised
		14	3.2 R8C/17 Group; (program area) → (program ROM), (data area) → (data flash) revised Figure 3.2 Memory Map of R8C/17 Group revised
		17	Table 4.3 SFR Information(3); 0085h: "Prescaler Z" → "Prescaler Z Register" 0086h: "Timer Z Secondary" → "Timer Z Secondary Register" 0087h: "Timer Z Primary" → "Timer Z Primary Register" 008Ch: "Prescaler X" → "Prescaler X Register" 008Dh: "Timer X" → "Timer X Register" 0090h, 0091h: "Timer C" → "Timer C Register" revised
		21	Table 5.4 Flash Memory (Program ROM) Electrical Characteristics; • NOTES 1 to 7 added • "Topr" → "Ambient temperature", "(Program area)" → "(Program ROM)" revised
		22	Table 5.5 Flash Memory (Data flash Block A, Block B) Electrical Characteristics; • NOTE1 revised, NOTE9 added • "Topr" → "Ambient temperature", "(Program area)" → "(Program ROM)" revised
		23	Figure 5.2 Time delay from Suspend Request until Erase Suspend revised Table 5.7 Voltage Detection 2 Circuit Electrical Characteristics; NOTE1 revised
		24	Table 5.8 Reset Circuit Electrical Characteristics (When Using Voltage Monitor 1 Reset); NOTE2 revised Table 5.9 Reset Circuit Electrical Characteristics (When Not Using Voltage Monitor 1 Reset); NOTE1 revised
		25	Table 5.10 High-speed On-Chip Oscillator Circuit Electrical Characteristics revised
		26	Table 5.12 Timing Requirements of I2C bus Interface (IIC); NOTE1 revised
		28	Table 5.14 Electrical Characteristics (2) [Vcc = 5V] revised
		29	"Timing Requirements (Unless ... at Ta = 25°C) [VCC = 5V]" → "Timing Requirements (Unless ... at Topr = 25°C) [VCC = 5V]" revised
		32	Table 5.18 Serial Interface; "35" → "50", "80" → "50"
		33	Table 5.21 Electrical Characteristics (4) [Vcc = 3V] revised "Timing requirements (Unless ... at Ta = 25°C) [VCC = 3V]" → "Timing requirements (Unless ... at Topr = 25°C) [VCC = 3V]" revised
		35	Table 5.25 Serial Interface; "55" → "70", "160" → "70"
			Package Dimensions; Package "PRDP0020BA-A" deleted

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